



Features

- BV_{CEO} > 450V
- BV_{CES} > 700V
- BV_{EBO} > 9V
- I_C = 3.2A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

450V NPN HIGH VOLTAGE POWER TRANSISTOR

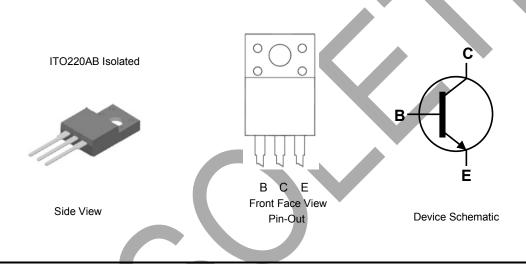
Mechanical Data

- Case: ITO220AB (Type BR)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish;
 Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 1500mg (Approximate)

Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting



Ordering Information (Note 4)

	Product	Package	Marking	Quantity		
	APT13005STF-G1	ITO220AB	APT13005STF-G1	1000 per Box in Tubes		
Notes:	1 EU Directive 2002/95/EC (BoHS) 2011/65/EU (BoHS 2) & 2015/863/EU (BoHS 3) compliant. All applicable BoHS exemptions applied					

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Manufacturers' Code Marking
 APT13005STF-G1 = Product Type Marking ID
 YWW = Date Code Marking
 e.g. 012 = Year 2020, Week 12.
 8 = Assembly Site Code
 XX = Batch Number



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V _{BE} = 0V)	V _{CES}	700	V
Collector-Emitter Voltage	V _{CEO}	450	V
Emitter-Base Voltage	V _{EBO}	9	V
Continuous Collector Current	Ι _C	3.2	А
Peak Pulse Collector Current	ICM	6.4	А
Continuous Base Current	IB	1.6	А
Peak Pulse Base Current	IBM	3.2	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

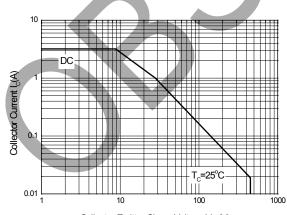
Characteristic	Symbol	Value	Unit
Power Dissipation	Po	28	W
Thermal Resistance, Junction to Case	R _{θJC}	4.5	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +150	°C

ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Areas (@T_A = +25°C, unless otherwise specified.)



Collector-Emitter Clamp Voltage $V_{CF}(V)$

Safe Operating Areas (ITO220AB Package)



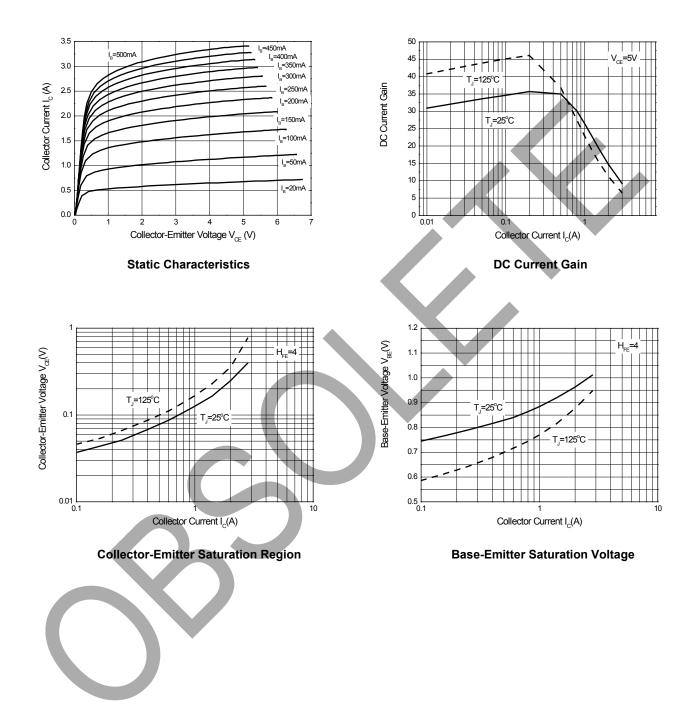
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV _{CES}	700	—	—	V	I _C = 100μA, V _{BE} = 0V
Collector-Emitter Breakdown Voltage	BV _{CEO}	450	—	—	V	I _C = 100μA
Emitter-Base Breakdown Voltage	BV _{EBO}	9	—	—	V	I _E = 100μA
Collector Cutoff Current	I _{CEV}	_	—	10	μA	V _{CE} = 700V, V _{BE} = -1.5V
DC Current Transfer Static Ratio (Note 6)	hee	20	_	35	_	I _C = 1A, V _{CE} = 5V
	h _{FE}	11	—	35		$I_{C} = 2A, V_{CE} = 5V$
		—	—	0.3		I _C = 1A, I _B = 0.2A
Collector-Emitter Saturation Voltage (Note 6)	V _{CE(sat)}	—		0.6		1 _C = 2A, I _B = 0.5A
		—	—	1.0		I _C = 3A, I _B = 0.75A
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}		_	1.2	N	I _C = 1A, 1 _B = 0.2A
	V BE(sat)	—	—	1.4	v	$I_{\rm C} = 2A, I_{\rm B} = 0.5A$
Output Capacitance	C _{obo}		35	—	рF	V _{CB} = 10V, f = 0.1MHz
Transition Frequency	ft	4	_		MHz	I _C = 0.5A, V _{CE} = 10V
Turn-on Time with Resistive Load	t _{on}	_	_	0.7		04.1/ 4051/
Storage Time with Resistive Load	ts	_	—	4.5	μs	$I_{C} = 2A, V_{CC} = 125V,$ $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t _f	_		0.8		1B11B2 - 0.4A

Note: 6. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

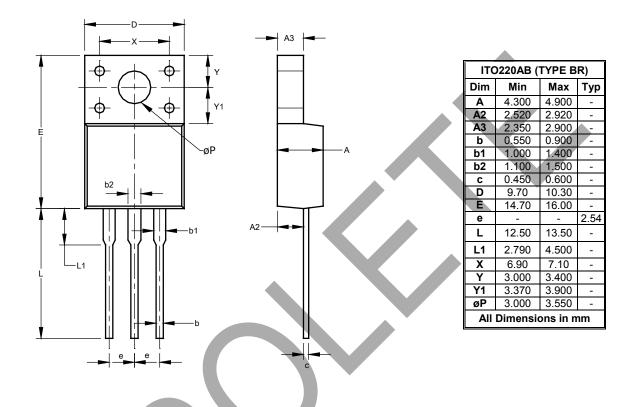




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

ITO220AB (TYPE BR)



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.





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